NSN 5961-01-325-0453

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Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

Between 0.250 inches and 0.328 inches

Overall Width:

Between 0.990 inches and 1.050 inches

End Application:

Indicator group an/spa-25g

Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Field Force Effect Type:

Electrostatic charge

Features Provided:

Hermetically sealed case and electrostatic sensitive

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 drain to source voltage

Current Rating Per Characteristic:

8.00 amperes source cutoff current of standard range

Power Rating Per Characteristic:

40.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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